NSN 5962-01-253-1561

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Body Length:	
1.290 inches	
Body Width:	
0.610 inches	
Body Height:	
0.150 inches	
Maximum Power D	ssipation Rating:
1.0 watts	
Operating Tempura	iture Range:
-55.0/+125.0 degree	s celsius
Storage Tempurati	ire Range:
-65.0/+150.0 degree	s celsius
Features Provided	
Schottky and progra	mmable and bipolar
nclosure Material:	
Ceramic	
Inclosure Configur	ation:
Dual-in-line	
Output Logic Form	:
Transistor-transistor	logic
Input Circuit Patter	n:
14 input	
Case Outline Sour	e And Designator:
D-3 mil-m-38510	
Terminal Surface T	reatment:
Solder	
Voltage Rating And	I Type Per Characteristic:
7.0 volts power sou	rce
Time Rating Per Cl	acteristic:
100.00 nanosecond	s propagation delay time, low to high level output and 100.00 nanoseconds propagation delay time, high to low level
output	
Memory Device Ty	be:
Rom	
Memory Capacity:	
Unknown	
Test Data Docume	nt:
96906-mil-std-883 s	andard (includes industry or association standards, individual manufactureer standards, etc.).
Terminal Type And	Quantity:
24 printed circuit	
Shelf Life:	
N/a	
Unit Of Measure:	

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Demilitarization:

Yes - demil/mli

Fiig:

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